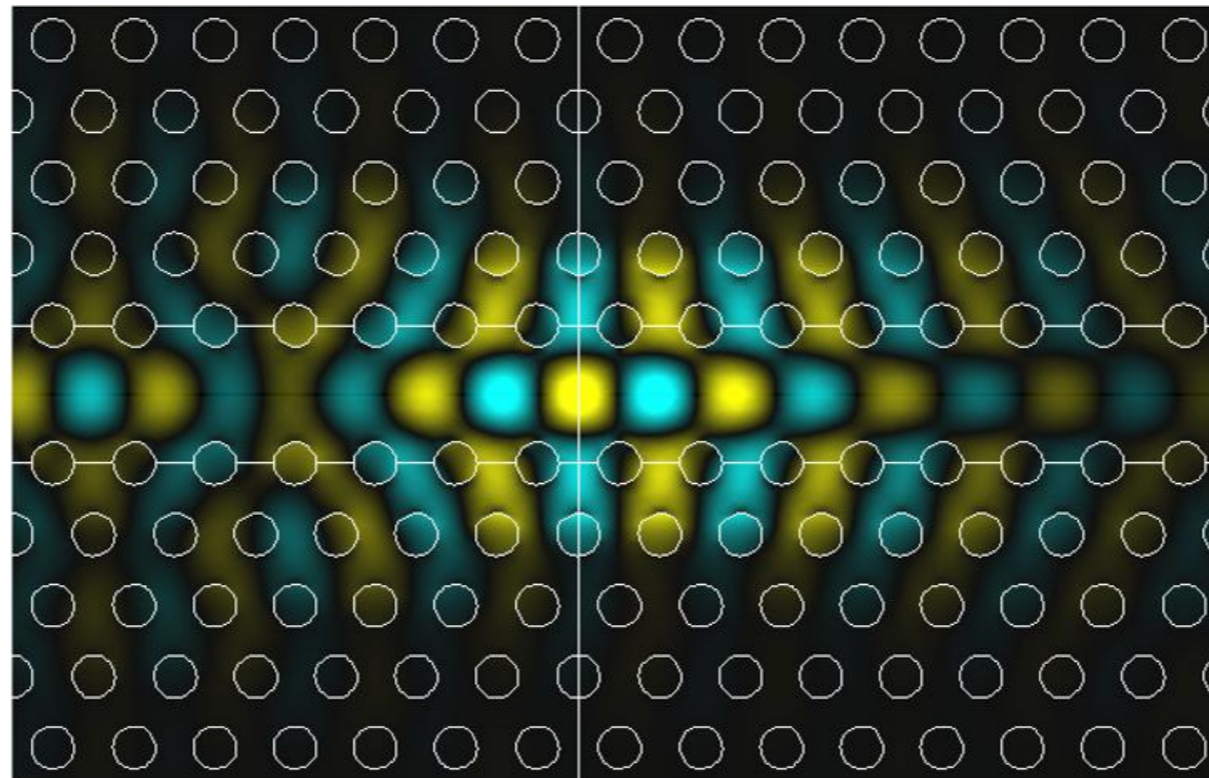




Characterization of a 3-D Photonic Crystal Structure Using Port and S-Parameter Analysis

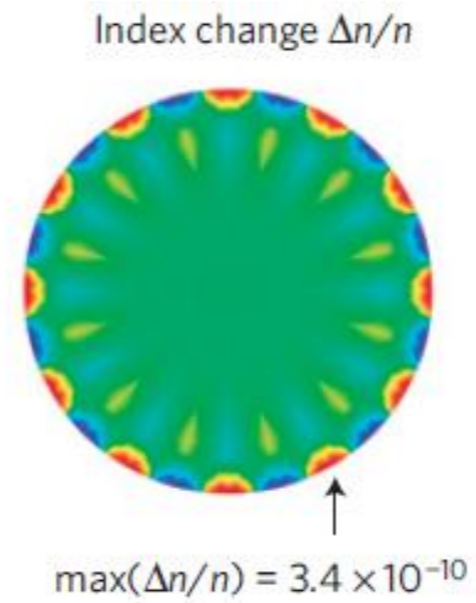
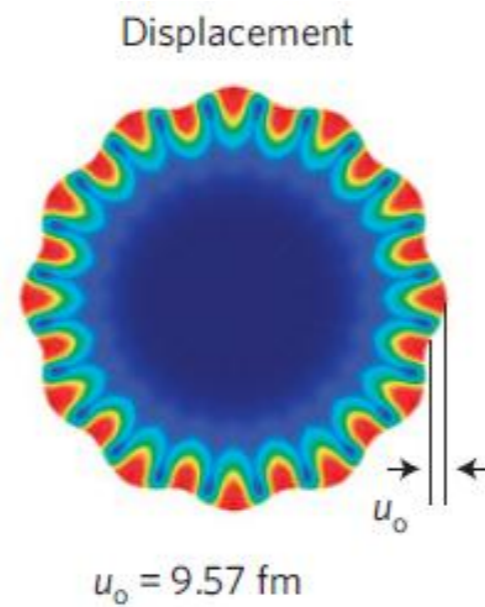
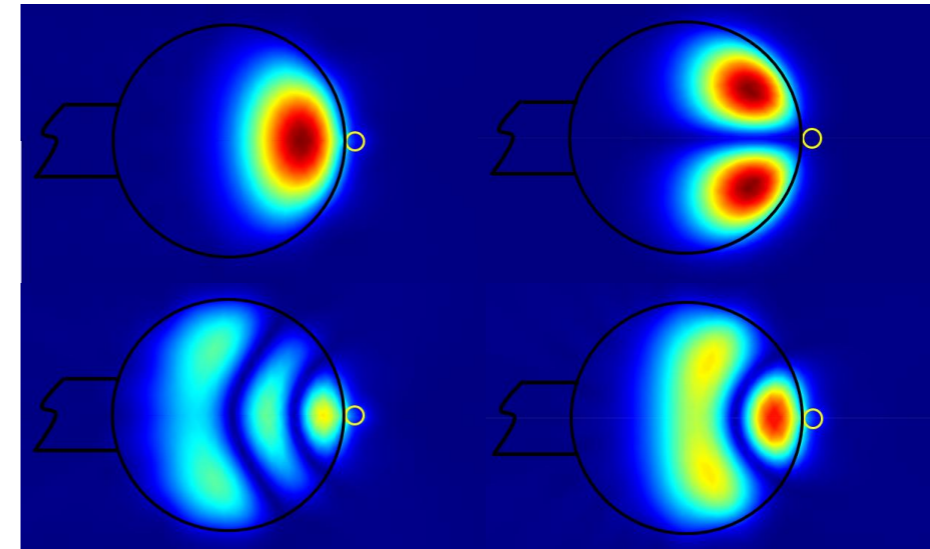
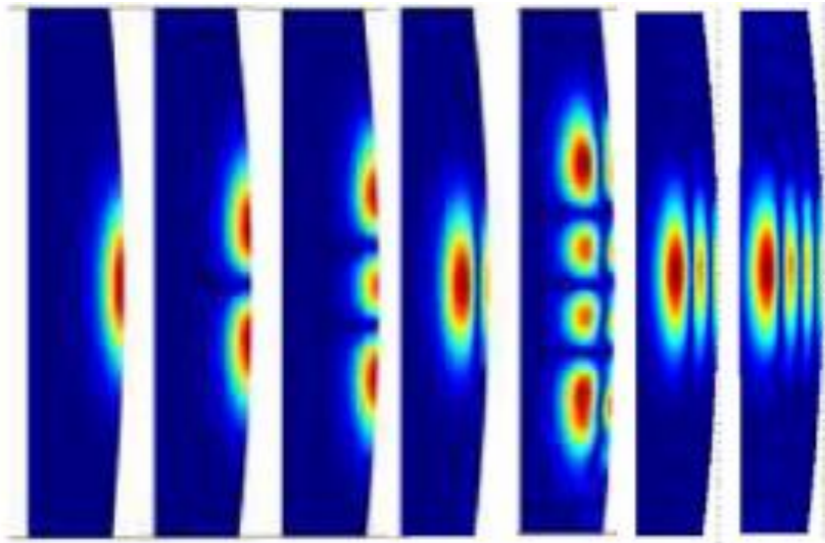
M. Dong^{*1}, M. Tomes¹, M. Eichenfield², M. Jarrahi¹, T. Carmon¹



¹University of Michigan, Ann Arbor, MI, USA

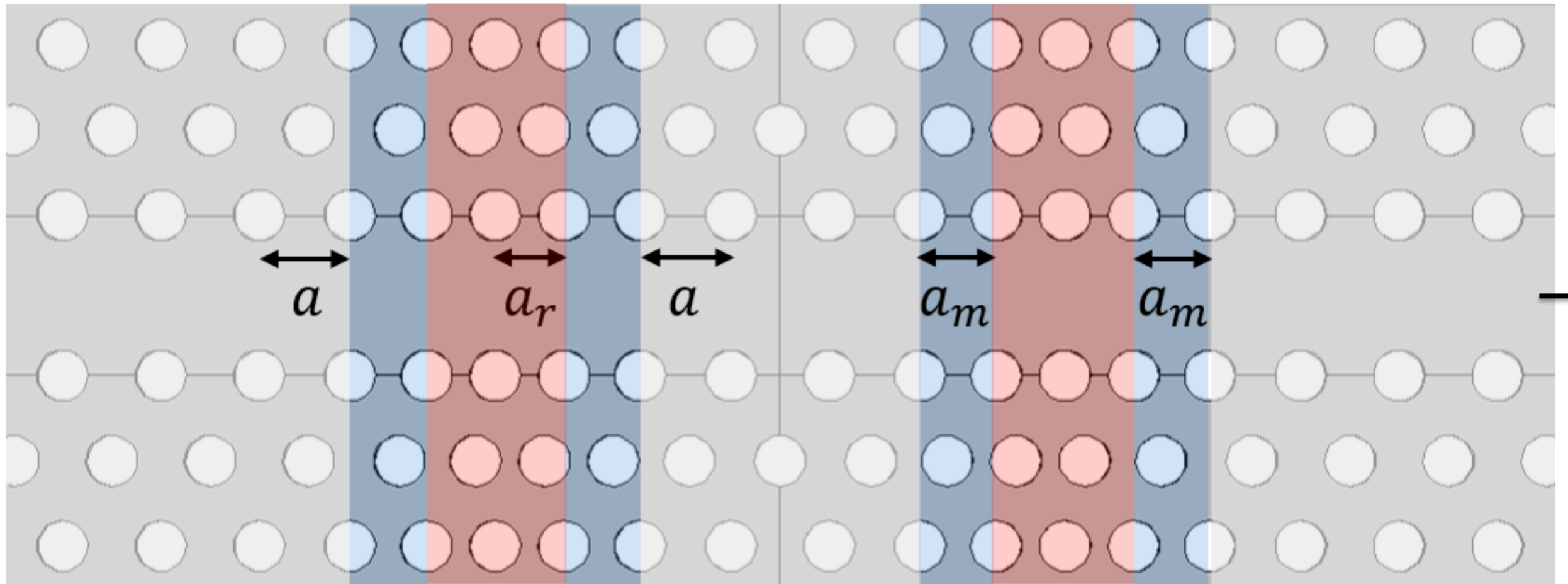
²Sandia National Laboratories, Albuquerque, New Mexico, USA

*Corresponding author: 3115 ERB, Ann Arbor, MI 48105, USA,
markdong@umich.edu



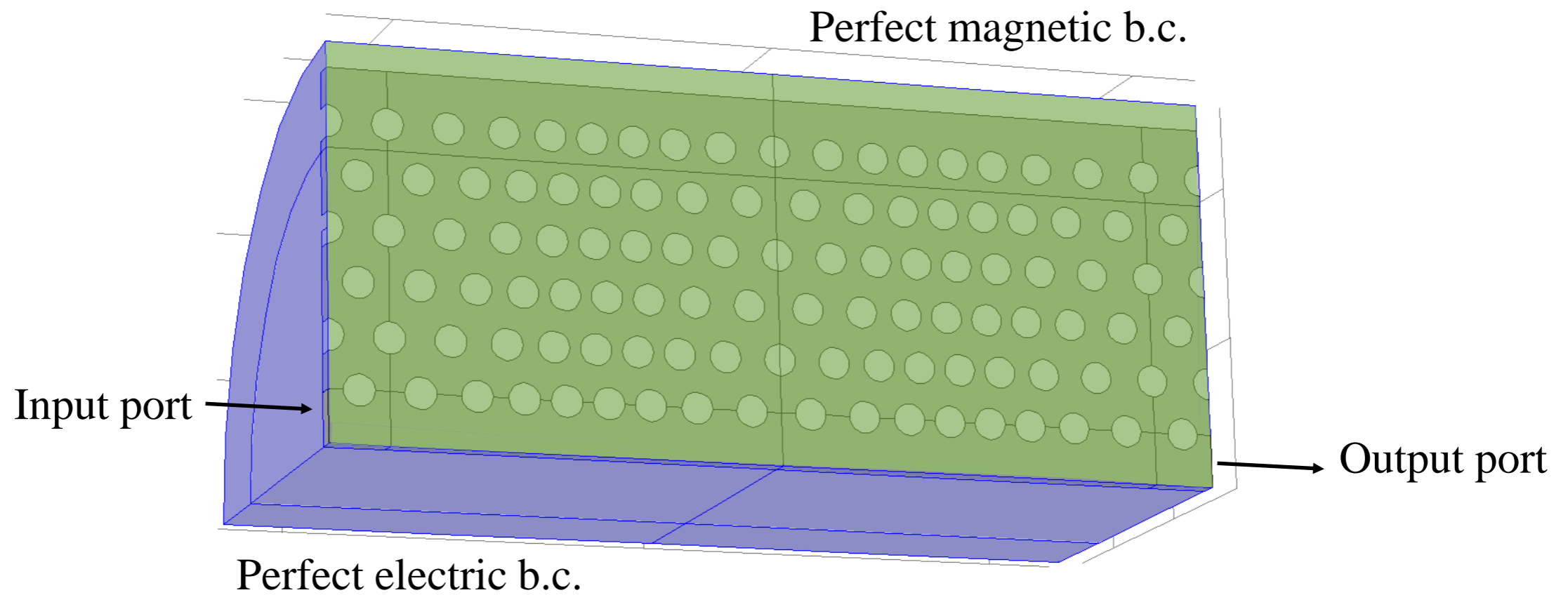


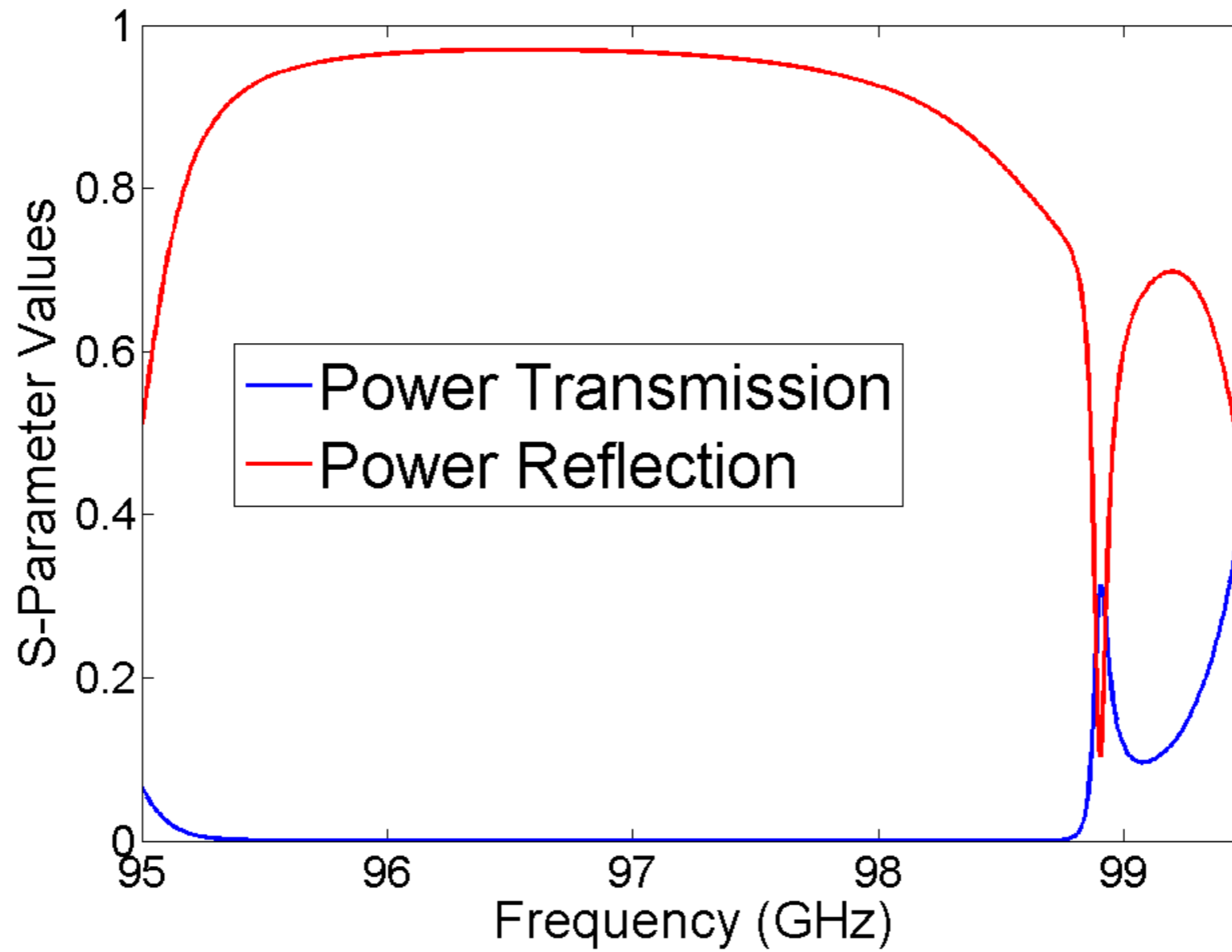
Geometry





Boundary Conditions



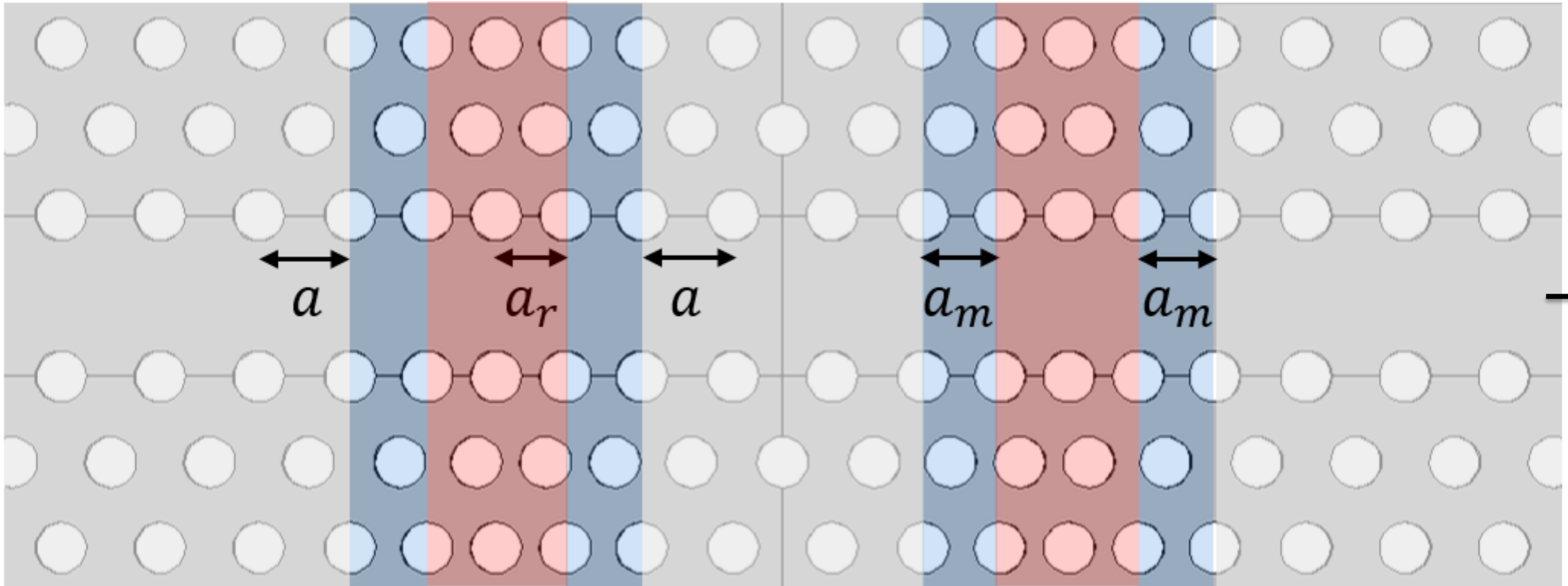




Geometry

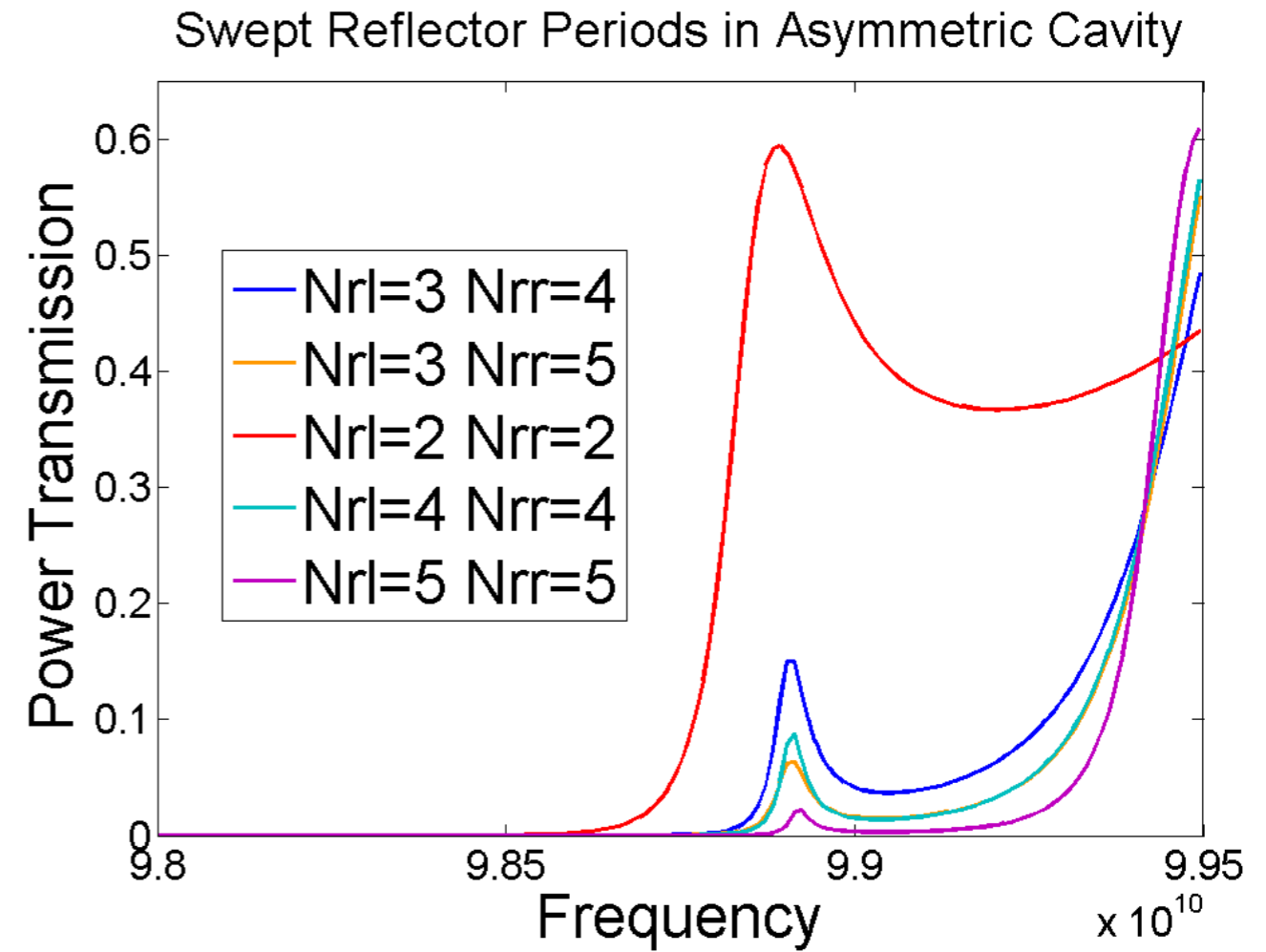
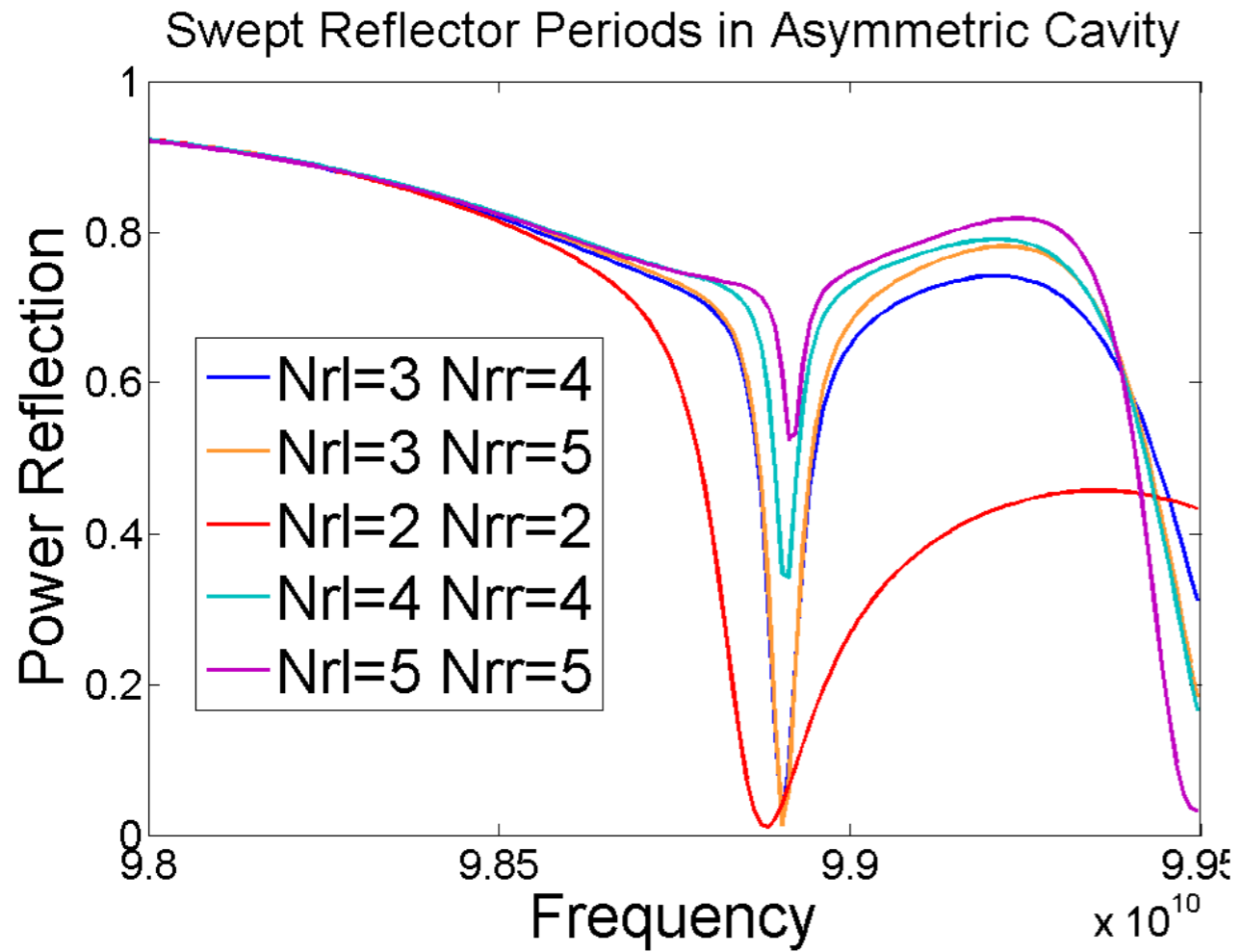
Nrl

Nrr





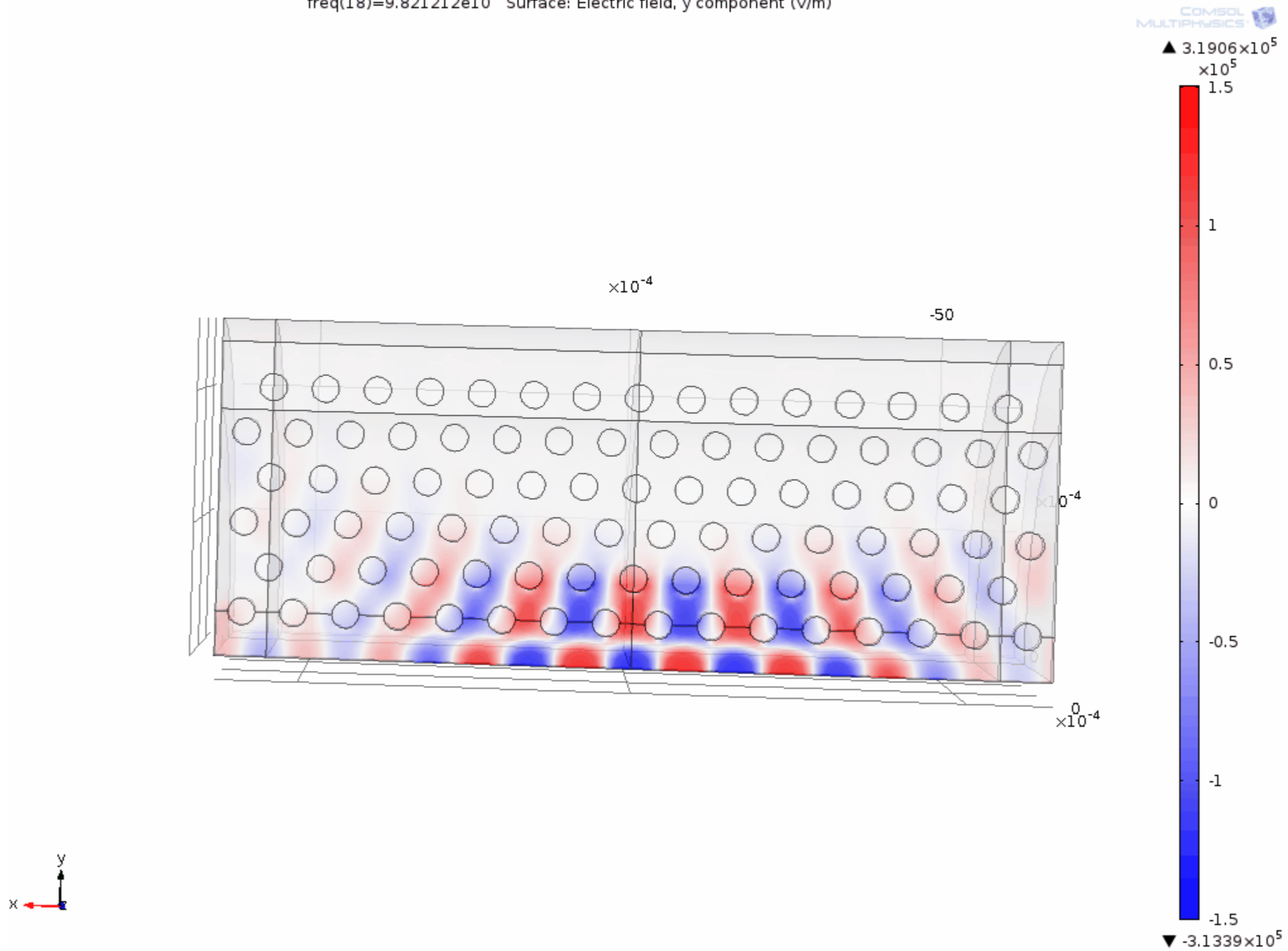
Results





Results – Animation without cavity

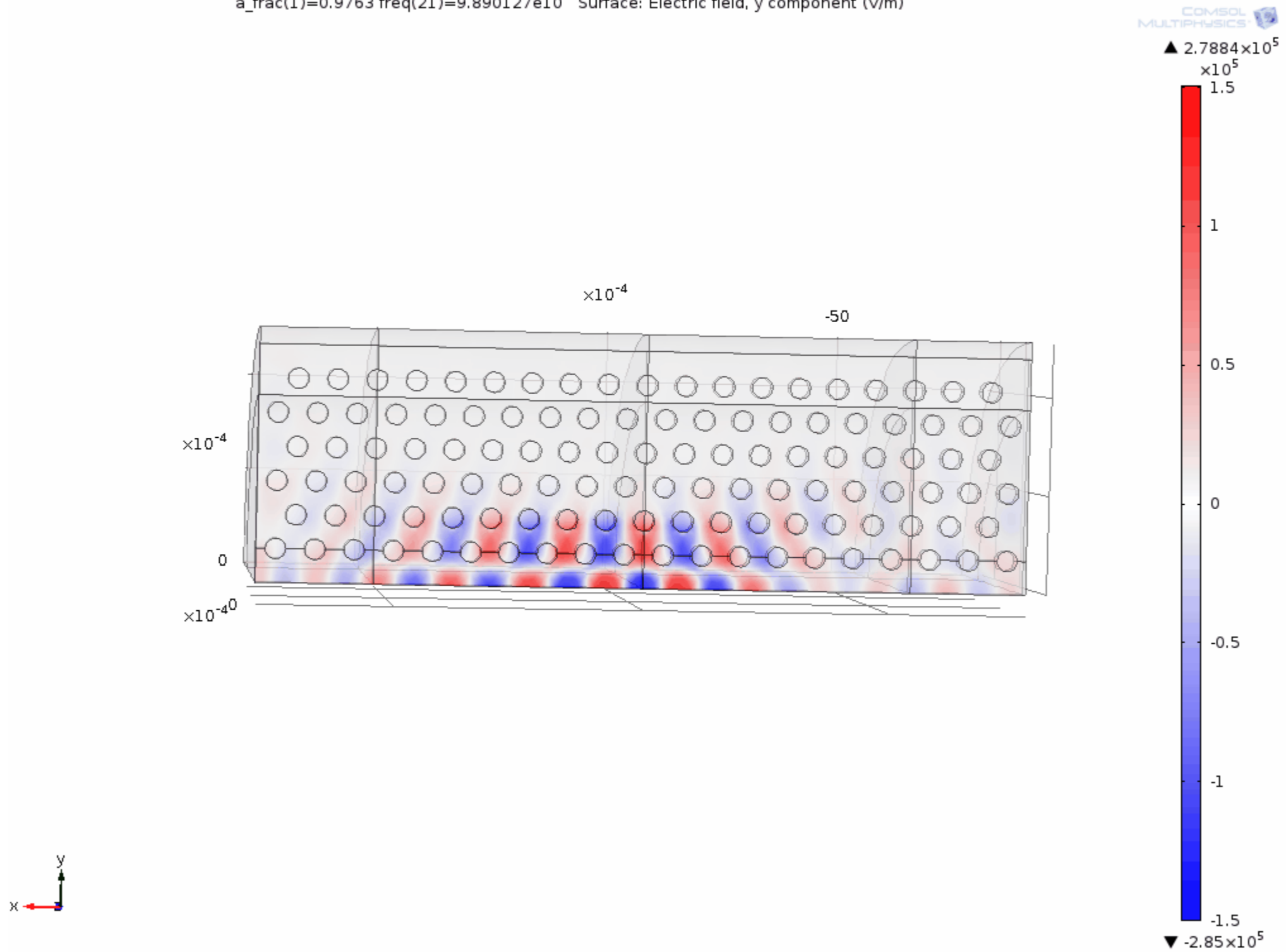
freq(18)=9.821212e10 Surface: Electric field, y component (V/m)





Results – Animation with cavity

a_frac(1)=0.9763 freq(21)=9.890127e10 Surface: Electric field, y component (V/m)





- Optimizing the input field profile
- External coupling into photonic crystal waveguide
- Fabrication and testing of devices



Acknowledgements

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for their software support and services.



Questions?